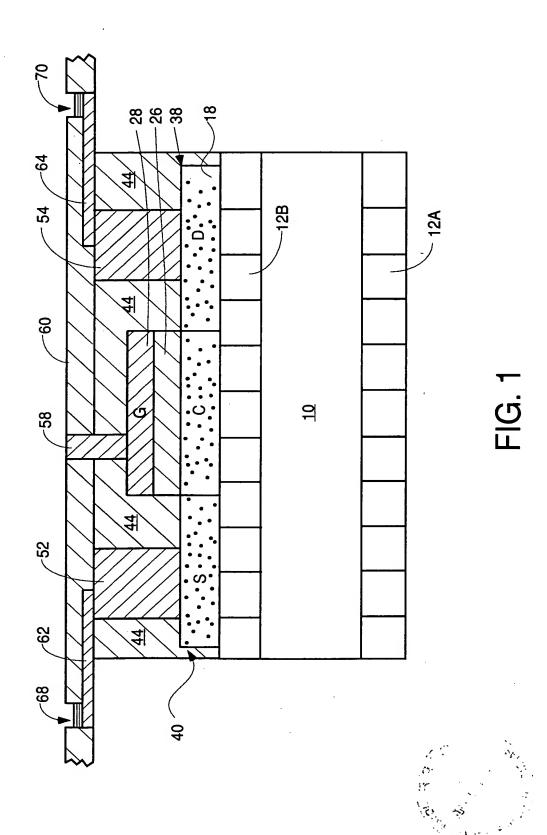
63 Inventor: REDDY Docket N .: SMA-0 IVE, RELIABLE, PLANAR RFID TAG STRUCTURE

D METHOD FOR

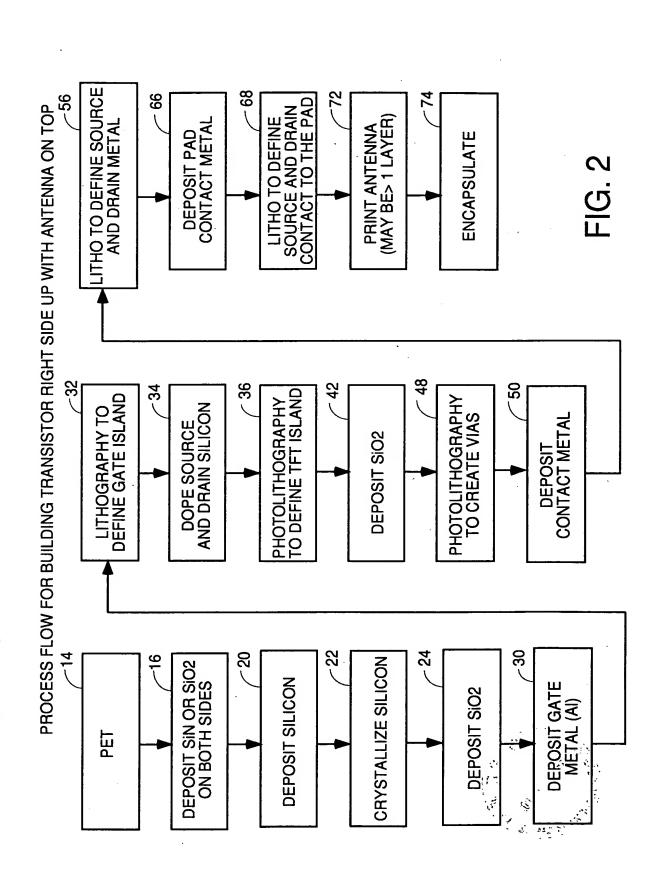
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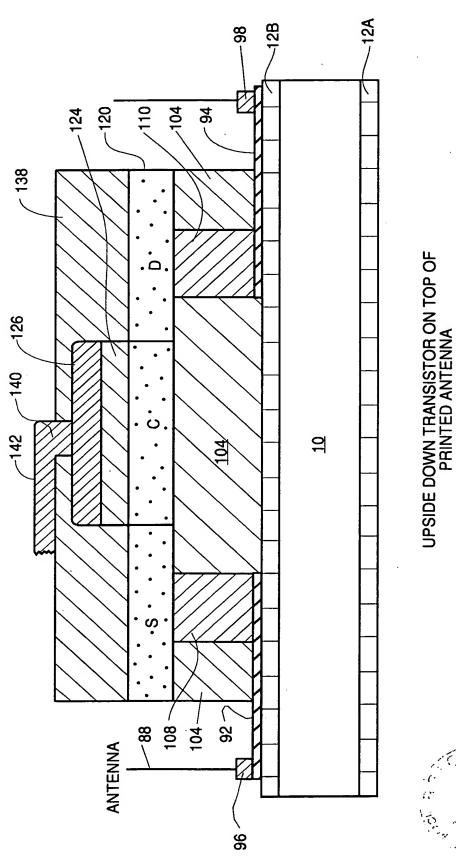
MAKING SAME

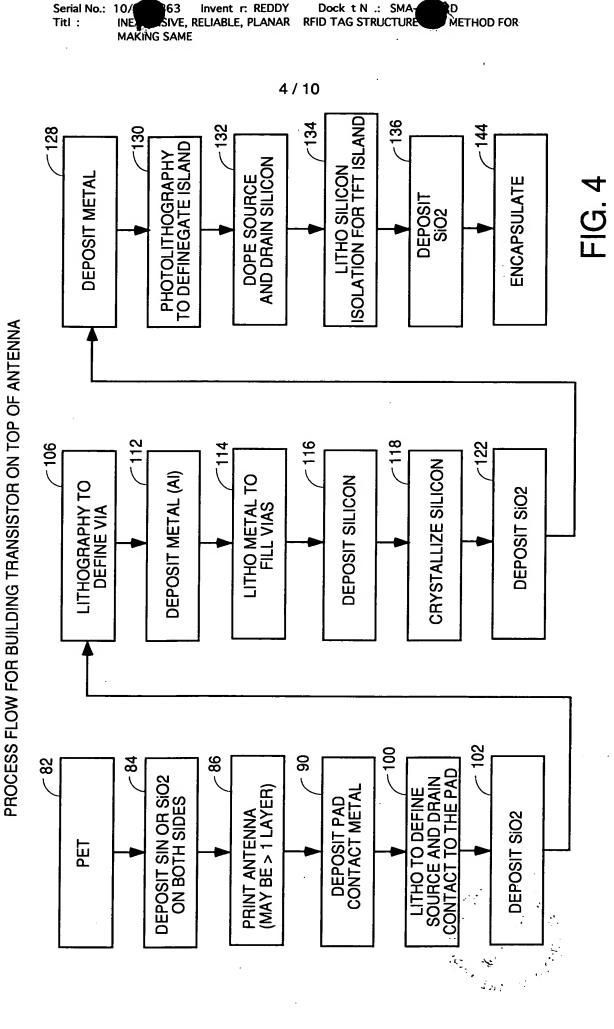
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D METHOD FOR

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INEXESSIVE, RELIABLE, PLANAR RFID TAG STRUCTURE MAKING SAME

D METHOD FOR

5/10

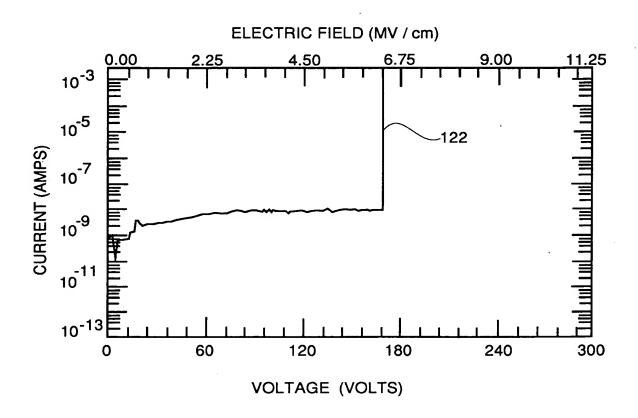


FIG. 5



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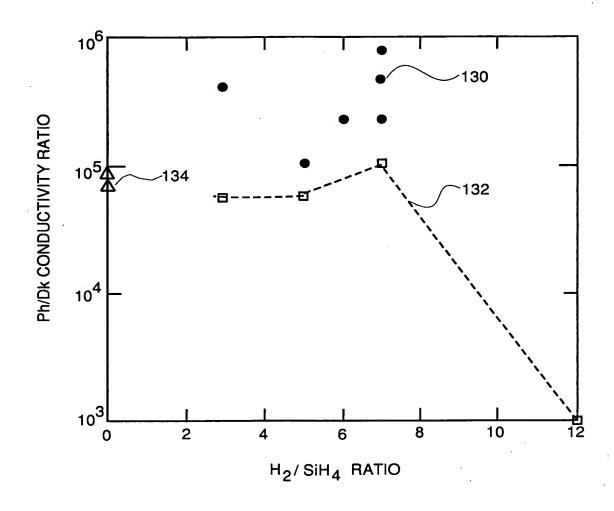
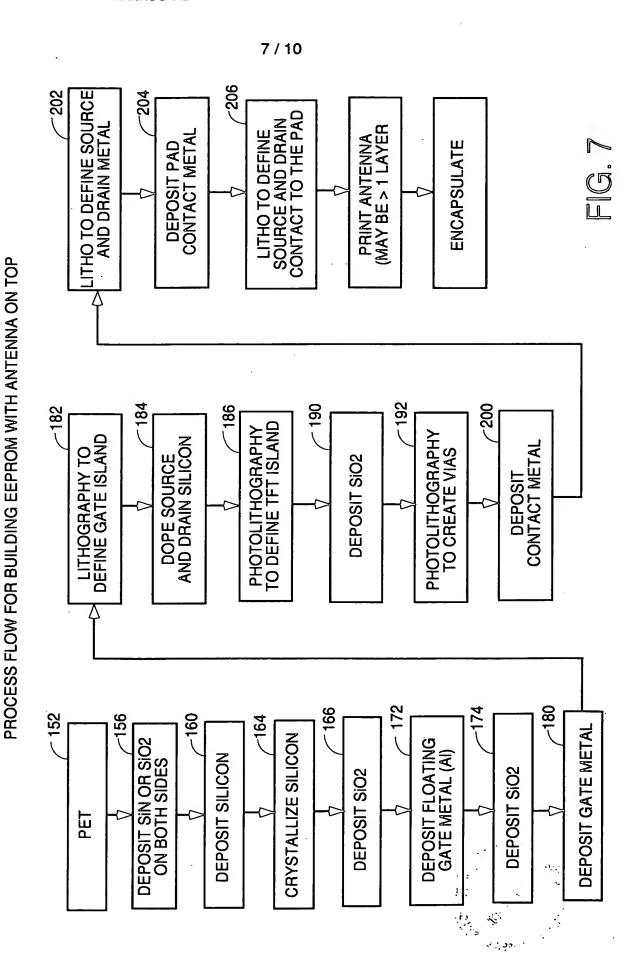
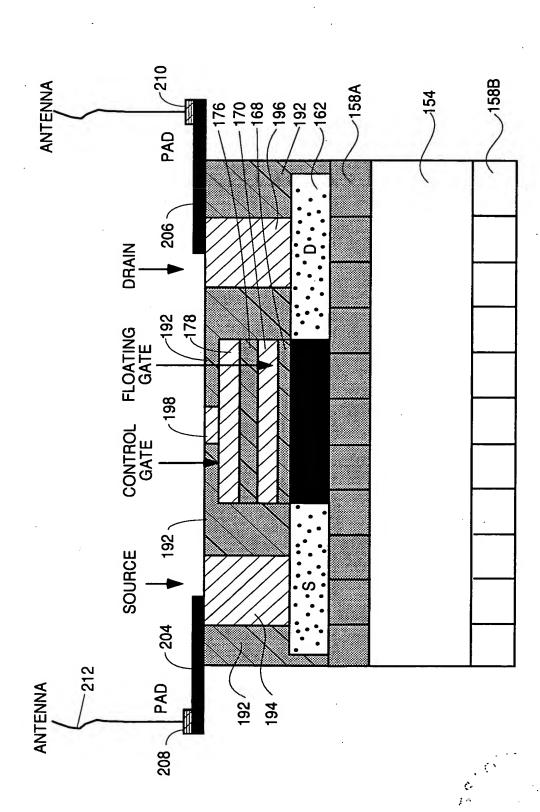


FIG. 6



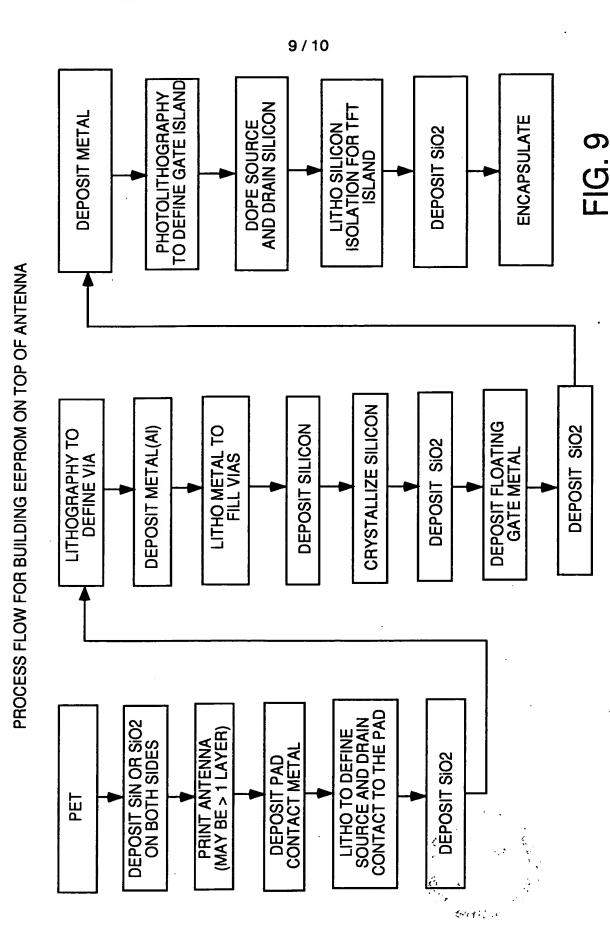
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SCHEMATIC OF A SINGLE EEPROM BUILT ON PET WITH THE CONTACT PADS AND THE ANTENNA PRINTED ON TOP OF THE TRANSISTOR; GATE WILL BE CONNECTED TO THE TRANSISTORS (IN ACTUAL DEVICES MULTIPLE TRANSISTORS AND EEPROM WILL BE CONNECTED TO THE CONTACT PADS)

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MAKING SAME

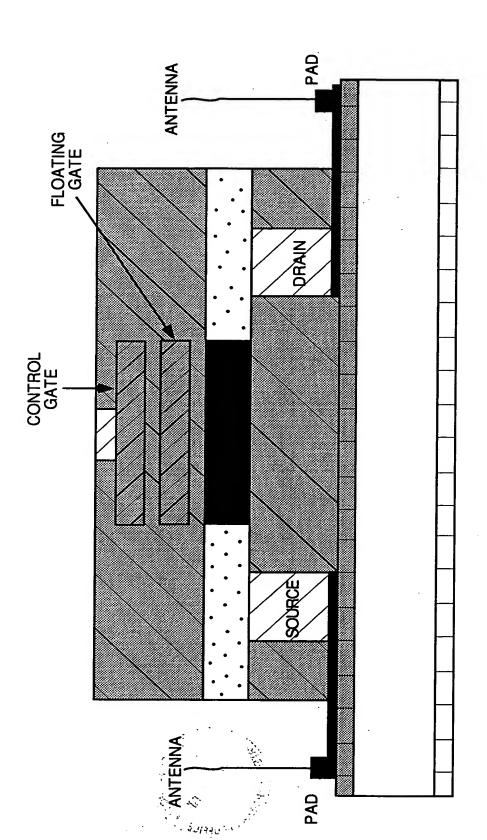


33 Inv ntor: REDDY Dock t N .: SMA-(IVE, RELIABLE, PLANAR RFID TAG STRUCTURE

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MAKING SAME

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SCHEMATIC OF A SINGLE EEPROM BUILT ON TOP OF THE PRINTED ANTENNA (IN ACTUAL DEVICES EEPROM AND MULTIPLE TRANSISTORS WILL BE CONNECTED TO THE CONTACT PADS)

FIG. 10